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RJK03E6DPA

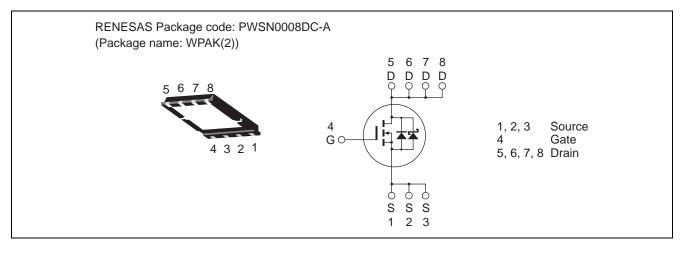
Silicon N Channel Power MOS FET with Schottky Barrier Diode Power Switching REJ03G1930-0210 Rev 2 10

Rev.2.10 May 20, 2010

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance $R_{DS(on)} = 3.8 \text{ m}\Omega \text{ typ.} (at V_{GS} = 8 \text{ V})$
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$	
ltem	Symbol	Ratings	Unit	
Drain to source voltage	V _{DSS}	30	V	
Gate to source voltage	V _{GSS}	±12	V	
Drain current	I _D	35	А	
Drain peak current	Note1 I _{D(pulse)}	140	А	
Body-drain diode reverse drain current	I _{DR}	35	А	
Avalanche current	I _{AP} Note 2	13	А	
Avalanche energy	E _{AR} Note 2	16.9	mJ	
Channel dissipation	Pch Note3	35	W	
Channel to case thermal impedance	θch-c ^{Note3}	3.57	°C/W	
Channel temperature	Tch	150	٥C	
Storage temperature	Tstg	-55 to +150	٥C	

Notes: 1. $PW \le 10 \ \mu s$, duty cycle $\le 1\%$

2. Value at Tch = 25°C, Rg \ge 50 Ω

3. Tc = 25°C



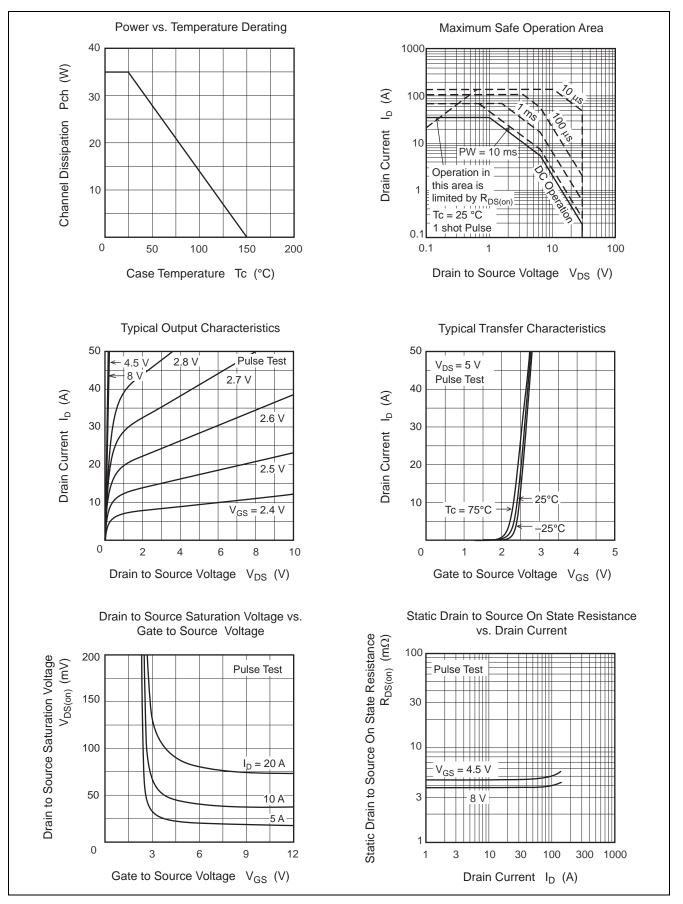
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	—	± 0.1	μΑ	$V_{GS} = \pm 12 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	mA	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	3.8	4.6	mΩ	$I_D = 17.5A, V_{GS} = 8.0 V^{Note4}$
resistance	R _{DS(on)}	_	4.6	5.6	mΩ	$I_D = 17.5A, V_{GS} = 4.5 V^{Note4}$
Forward transfer admittance	y _{fs}		83	_	S	$I_D = 17.5A, V_{DS} = 5 V^{Note4}$
Input capacitance	Ciss		2670	3740	pF	V _{DS} = 10 V
Output capacitance	Coss		320	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		200	_	pF	
Gate Resistance	Rg		1.7	3.4	Ω	
Total gate charge	Qg		20		nC	V _{DD} = 10 V
Gate to source charge	Qgs		7	_	nC	V _{GS} = 4.5 V I _D = 35 A
Gate to drain charge	Qgd		6.2		nC	
Turn-on delay time	t _{d(on)}		14		ns	V _{GS} = 8 V, I _D =17.5 A
Rise time	tr		5.4		ns	$V_{DD} \cong 10 \text{ V}$ $R_{L} = 0.57\Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}		52	_	ns	
Fall time	t _f		8		ns	
Body–drain diode forward voltage	V _{DF}	_	0.39		V	$I_F = 2 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}		24		ns	$I_F = 35 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 \text{ A}/\mu \text{s}$

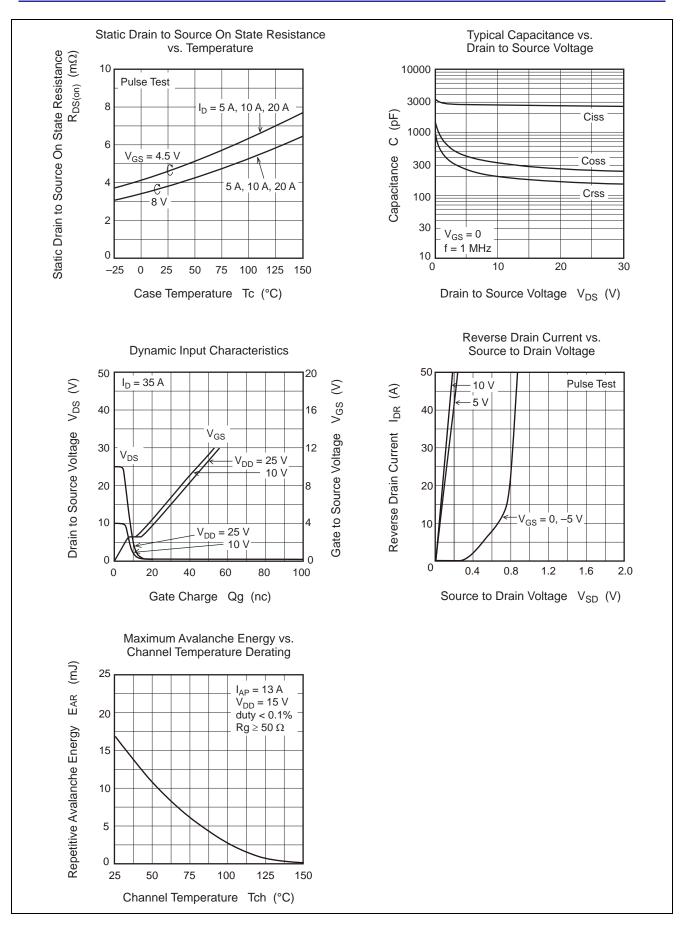
Notes: 4. Pulse test



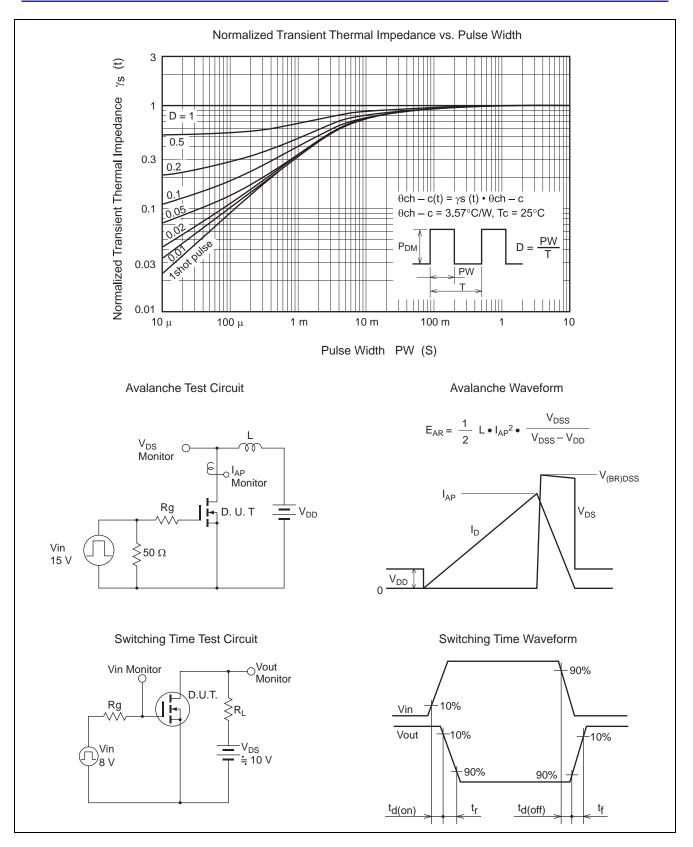
Main Characteristics





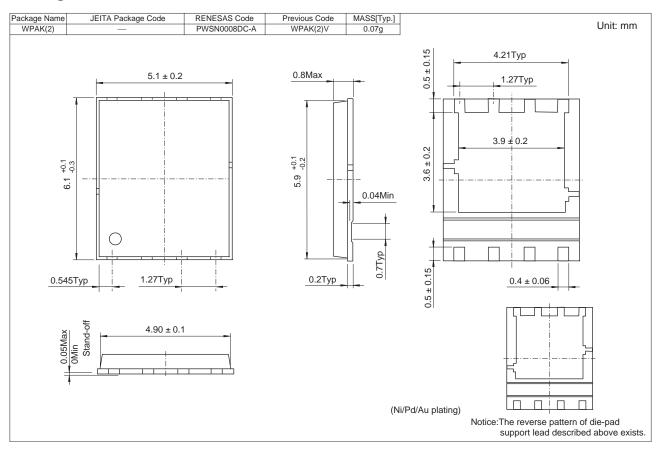








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RJK03E6DPA-00-J53	3000 pcs	Taping



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